

2MBI300XNA170-50

IGBT Modules

Power Module (X series)
1700V / 300A / 2-in-1 package

■ Features

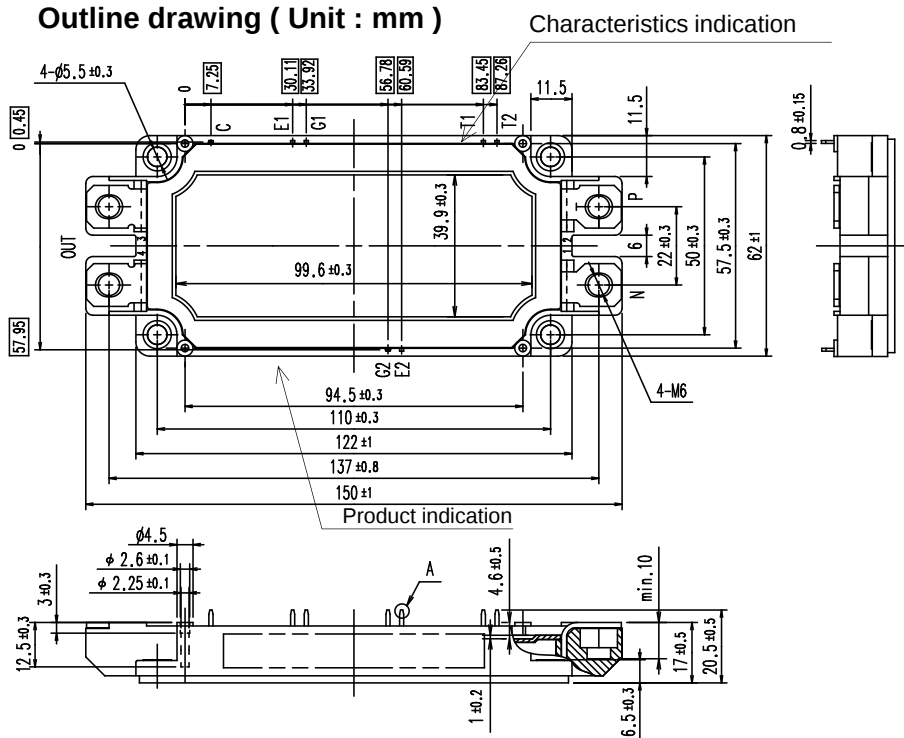
Low $V_{CE(sat)}$
Low Inductance Module structure
Solder pin terminals

■ Applications

Inverter for Motor Drives, AC and DC Servo Drives
Uninterruptible Power Supply Systems, Wind Turbines, PV Power Conditioning Systems



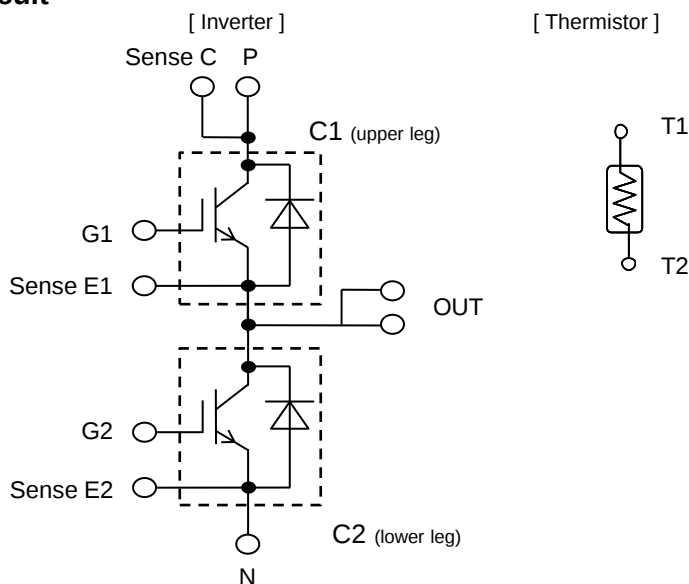
■ Outline drawing (Unit : mm)



NOTE) shows theoretical dimension and tolerance is ± 0.5

Weight: 350 g(typ.)

■ Equivalent Circuit



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■ Absolute Maximum Ratings (at $T_c = 25^\circ\text{C}$ unless otherwise specified)

Items		Symbols	Conditions		Maximum Ratings	Units
Collector-emitter voltage, gate-emitter short-circuited		V_{CES}			1700	V
Gate-emitter voltage, collector-emitter short-circuited		V_{GES}			± 20	V
Collector current		I_C	Continuous	$T_c = 100^\circ\text{C}$	300	A
Repetitive peak collector current		I_{CRM}	1ms		600	
Forward current		I_F			300	
Repetitive peak forward current		I_{FRM}	1ms		600	
Total power dissipation		P_{tot}	1 device		#REF!	W
Virtual junction temperature		T_{vj}			175	$^\circ\text{C}$
Operating junction temperature (under switching conditions)		T_{vjop}			175	
Case temperature		T_c			125	
Storage temperature		T_{stg}			-40 ~ 125	
Isolation voltage	between terminal and copper base (*1)	V_{isol}	AC: 1min.		3400	Vrms
	between thermistor and others (*2)					
Mounting torque of screws to heatsink (*3)		M_s	M5		6.0	N·m
Mounting torque of screws to terminals (*3)		M_t	M6		6.0	

(*1) All terminals should be connected together during the test.

(*2) Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

(*3) Recommendable Value: : Mounting torque of screws to heatsink 2.5 ~ 6.0 N·m (M5)
Recommendable Value: : Mounting torque of screws to terminals 3.5 ~ 6.0 N·m (M6)

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■ Electrical characteristics (at $T_{vj}=25^{\circ}\text{C}$ unless otherwise specified)

Items	Symbols	Conditions		Characteristics			Units
				min.	typ.	max.	
Collector-emitter cut-off current, gate-emitter short-circuited	I_{CES}	$V_{GE} = 0V$ $V_{CE} = 1700V$		-	-	150	μA
Gate leakage current, collector-emitter short-circuited	I_{GES}	$V_{CE}=0V, V_{GE}=\pm 20V$		-	-	300	nA
Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = 20V$ $I_C = 300mA$		6.0	6.5	7.0	V
Collector-emitter saturation voltage	$V_{CE(sat)}$ (terminal)	$V_{GE} = 15V$ $I_C = 300A$	$T_{vj}=25^{\circ}C$	-	#N/A	#N/A	V
	$V_{CE(sat)}$ (chip)		$T_{vj}=25^{\circ}C$	-	#N/A	#N/A	
			$T_{vj}=125^{\circ}C$	-	#N/A	-	
			$T_{vj}=150^{\circ}C$	-	#N/A	-	
			$T_{vj}=175^{\circ}C$	-	#N/A	-	
Internal gate resistance	r_g	-		-	3.33	-	Ω
Capacitance	C_{ies}	$V_{CE}=10V, V_{GE}=0V, f=1MHz$		-	#N/A	-	nF
	C_{oes}			-	#N/A	-	
	C_{res}			-	#N/A	-	
Gate charge	Q_G	$V_{CC} = 900V, I_C = 300A$ $V_{GE} = -15 \rightarrow +15V$		-	#REF!	-	μC
Forward voltage	V_F (terminal)	$V_{GE} = 0V$ $I_F = 300A$	$T_{vj}=25^{\circ}C$	-	#N/A	#N/A	V
	V_F (chip)		$T_{vj}=25^{\circ}C$	-	#N/A	#N/A	
			$T_{vj}=125^{\circ}C$	-	#N/A	-	
			$T_{vj}=150^{\circ}C$	-	#N/A	-	
			$T_{vj}=175^{\circ}C$	-	#N/A	-	
Switching time (*1)	$t_{d(on)}$	$V_{CC} = 900V$ $I_C, I_F = 300A$ $V_{GE} = \pm 15V$ $R_G = \pm 0.68\Omega$ $L_S = 35nH$	$T_{vj}=25^{\circ}C$	-	#N/A	-	μs
			$T_{vj}=125^{\circ}C$	-	#N/A	-	
			$T_{vj}=150^{\circ}C$	-	#N/A	-	
			$T_{vj}=175^{\circ}C$	-	#N/A	-	
	t_r		$T_{vj}=25^{\circ}C$	-	#N/A	-	
			$T_{vj}=125^{\circ}C$	-	#N/A	-	
			$T_{vj}=150^{\circ}C$	-	#N/A	-	
			$T_{vj}=175^{\circ}C$	-	#N/A	-	
	$t_{d(off)}$		$T_{vj}=25^{\circ}C$	-	#N/A	-	
			$T_{vj}=125^{\circ}C$	-	#N/A	-	
			$T_{vj}=150^{\circ}C$	-	#N/A	-	
			$T_{vj}=175^{\circ}C$	-	#N/A	-	
	t_f		$T_{vj}=25^{\circ}C$	-	#N/A	-	
			$T_{vj}=125^{\circ}C$	-	#N/A	-	
			$T_{vj}=150^{\circ}C$	-	#N/A	-	
			$T_{vj}=175^{\circ}C$	-	#N/A	-	
Reverse recovery time	t_{rr}	$T_{vj}=25^{\circ}C$	-	#N/A	-		
		$T_{vj}=125^{\circ}C$	-	#N/A	-		
		$T_{vj}=150^{\circ}C$	-	#N/A	-		
		$T_{vj}=175^{\circ}C$	-	#N/A	-		

(*1) Turn on time (t_{on}) = $t_{d(on)} + t_r$, Turn off time (t_{off}) = $t_{d(off)} + t_f$

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■ Electrical characteristics (at $T_{vj}=25^{\circ}\text{C}$ unless otherwise specified)

Items		Symbols	Conditions		Characteristics			Units
					min.	typ.	max.	
Switching loss (per pulse)		E_{on}	$V_{\text{CC}} = 900\text{V}$ $I_{\text{C}}, I_{\text{F}} = 300\text{A}$ $V_{\text{GE}} = \pm 15\text{ V}$ $R_{\text{G}} = \pm 0.68\Omega$ $L_{\text{S}} = 35\text{ nH}$	$T_{\text{vj}} = 25^{\circ}\text{C}$	-	#N/A	-	mJ
				$T_{\text{vj}} = 125^{\circ}\text{C}$	-	#N/A	-	
				$T_{\text{vj}} = 150^{\circ}\text{C}$	-	#N/A	-	
				$T_{\text{vj}} = 175^{\circ}\text{C}$	-	#N/A	-	
		E_{off}		$T_{\text{vj}} = 25^{\circ}\text{C}$	-	#N/A	-	
				$T_{\text{vj}} = 125^{\circ}\text{C}$	-	#N/A	-	
				$T_{\text{vj}} = 150^{\circ}\text{C}$	-	#N/A	-	
				$T_{\text{vj}} = 175^{\circ}\text{C}$	-	#N/A	-	
		E_{rr}		$T_{\text{vj}} = 25^{\circ}\text{C}$	-	#N/A	-	
				$T_{\text{vj}} = 125^{\circ}\text{C}$	-	#N/A	-	
				$T_{\text{vj}} = 150^{\circ}\text{C}$	-	#N/A	-	
				$T_{\text{vj}} = 175^{\circ}\text{C}$	-	#N/A	-	
Thermistor	Resistance	R	$T = 25^{\circ}\text{C}$	-	5000	-	Ω	
			$T = 100^{\circ}\text{C}$	465	495	520		
	B value	B	$T = 25/ 50^{\circ}\text{C}$	3305	3375	3450	K	

NOTICE:

The external gate resistance (R_G) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum R_G depends on circuit configuration and/or environment. We recommend that the R_G has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

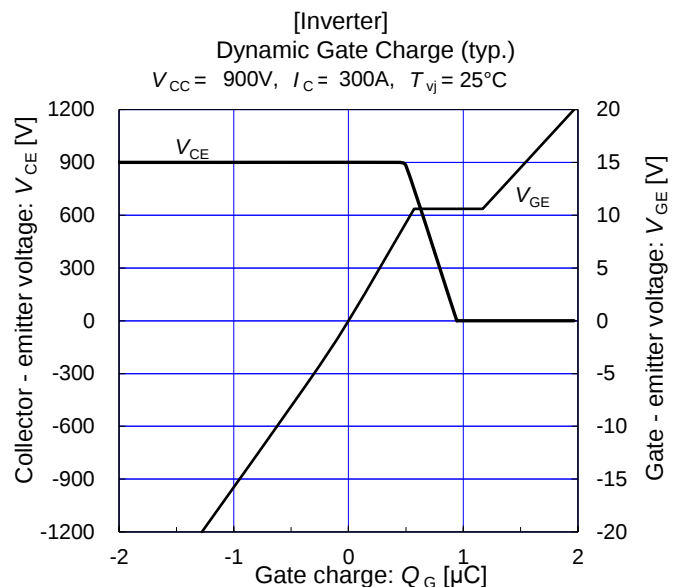
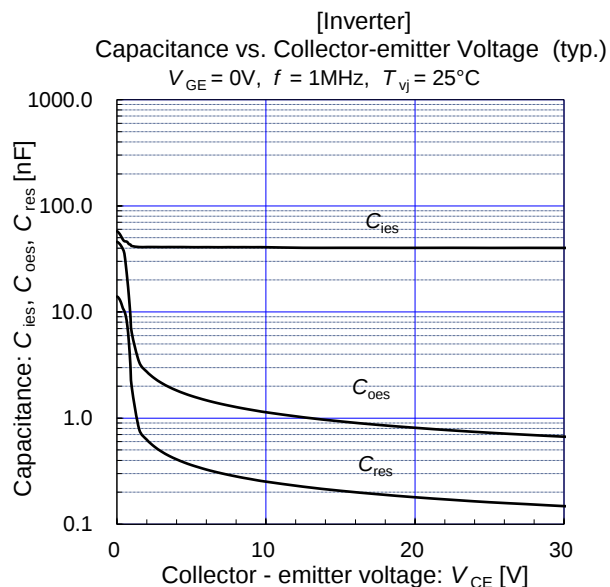
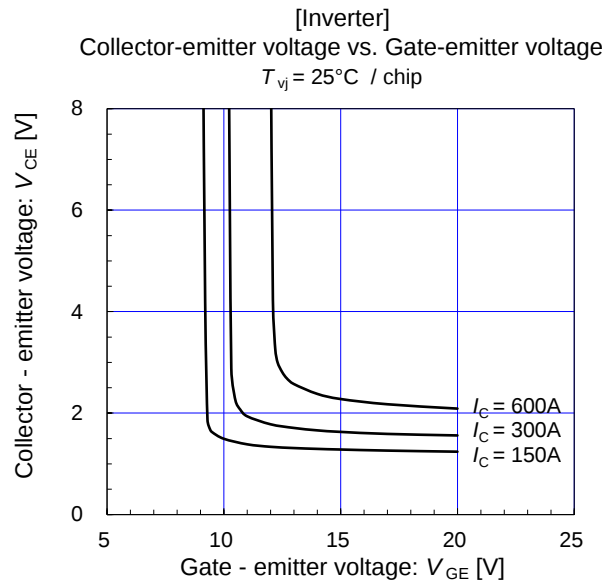
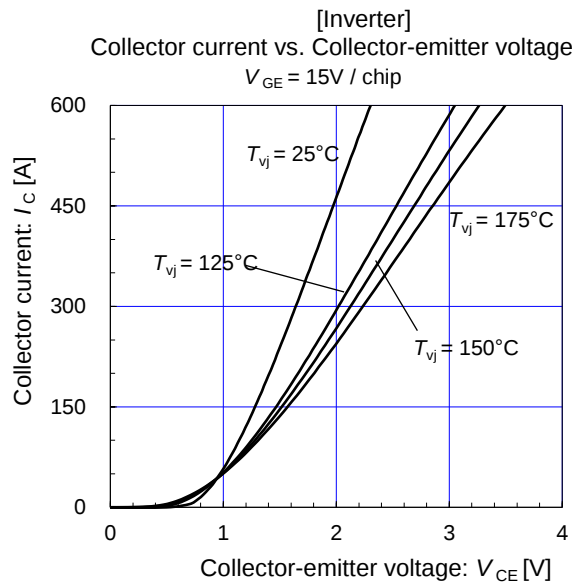
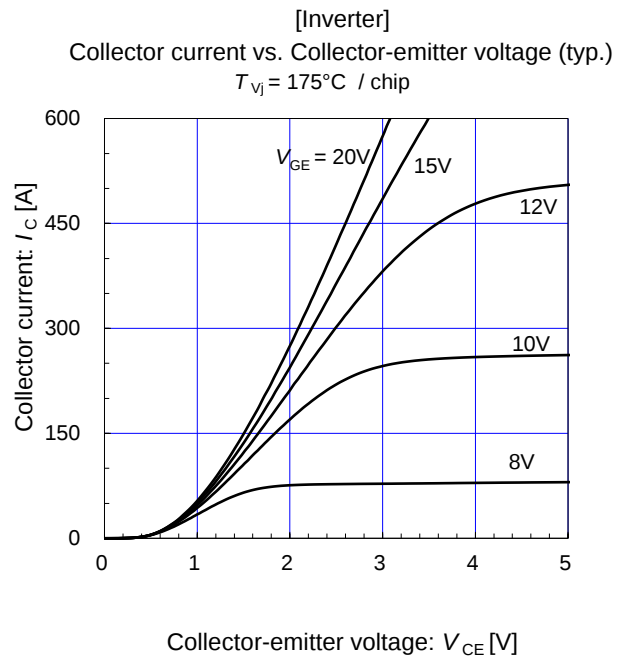
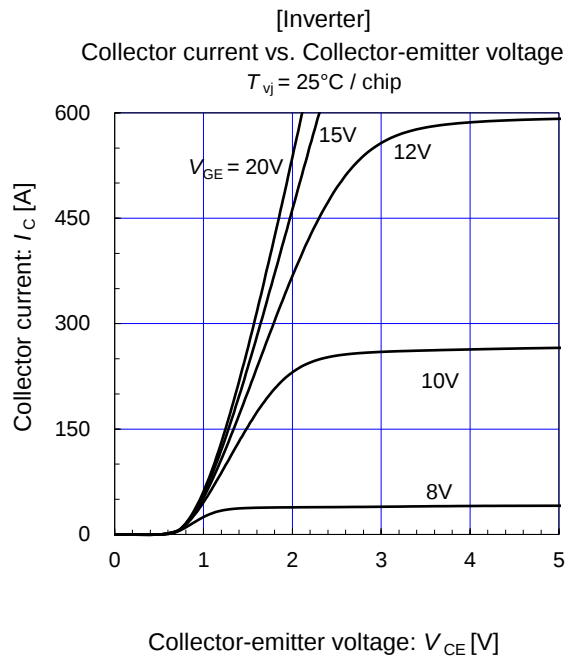
■ Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal resistance junction to case(1 device)	$R_{th(j-c)}$	Inverter IGBT	-	-	#REF!	K/W
		Inverter FWD	-	-	#REF!	
Thermal resistance case to heatsink(1 IGBT+1 FWD) (*1)	$R_{th(c-s)}$	with 1 W/(m·K) thermal greas	-	0.0167	-	

(*1) This is the value which is defined mounting on the additional heatsink with thermal grease.

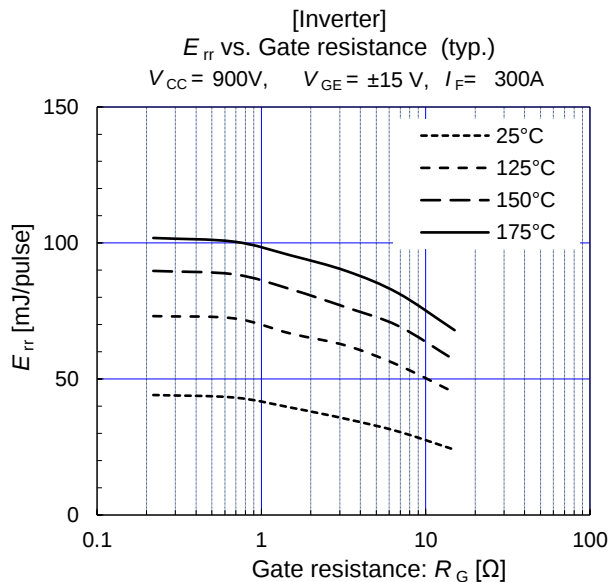
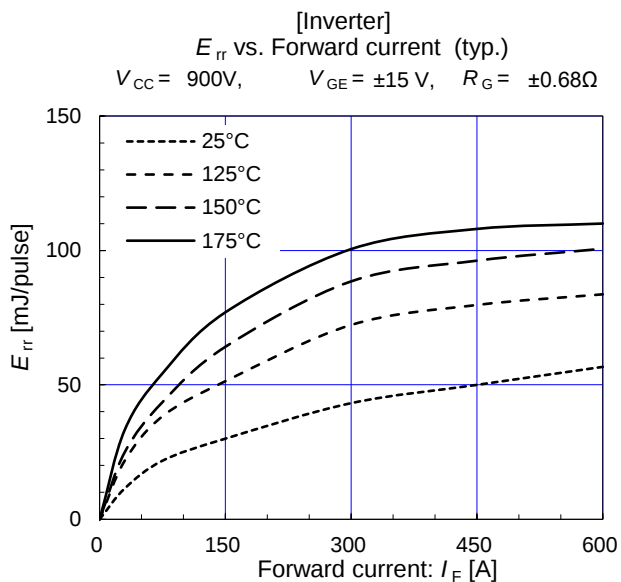
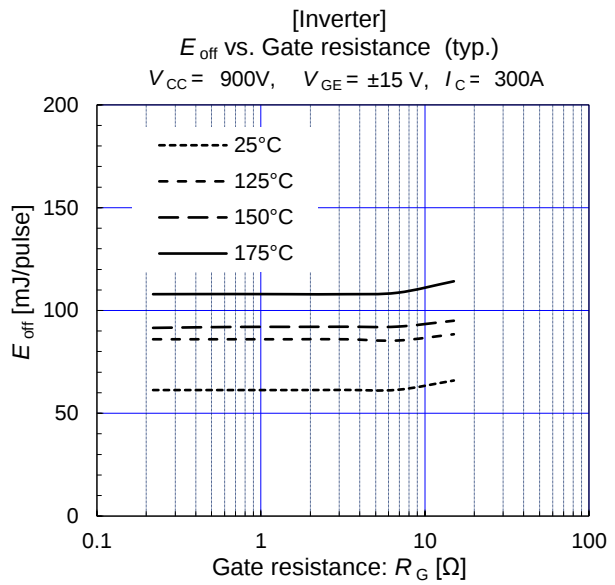
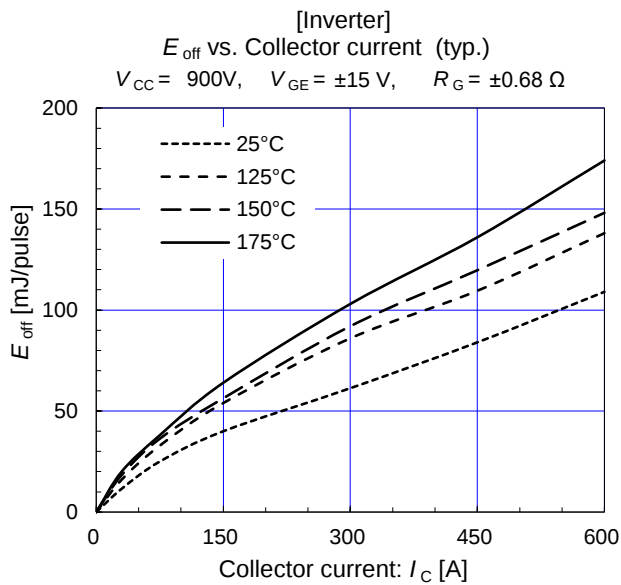
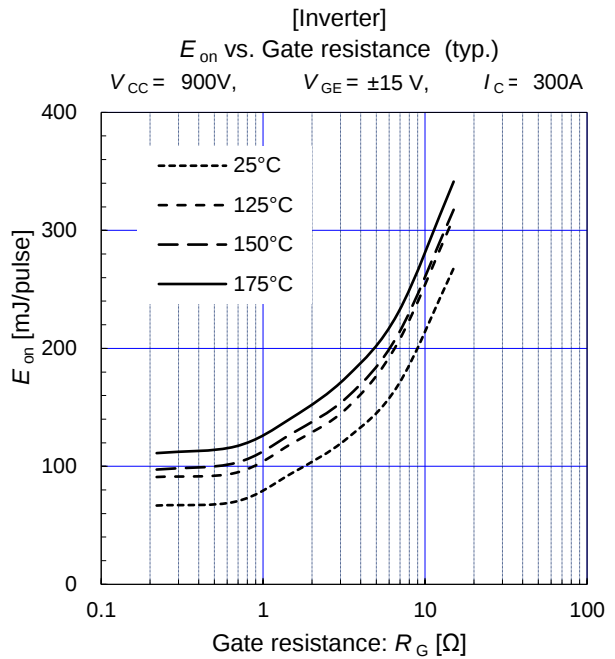
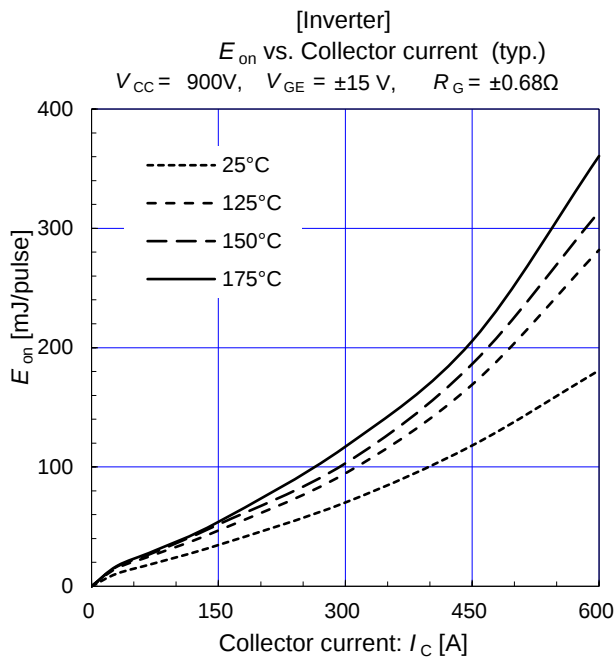
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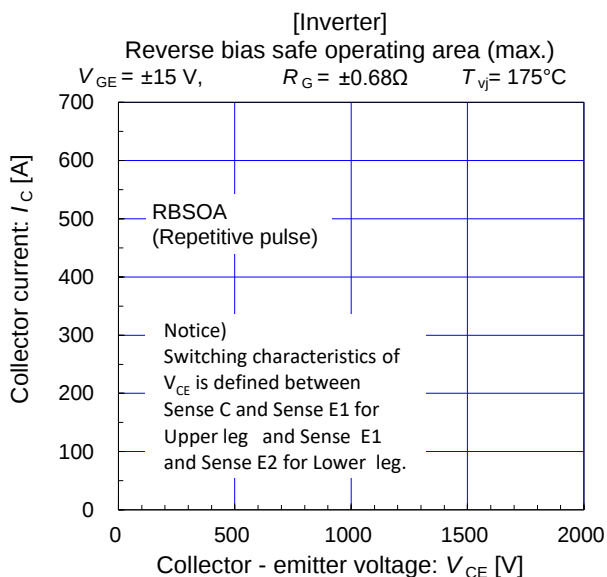
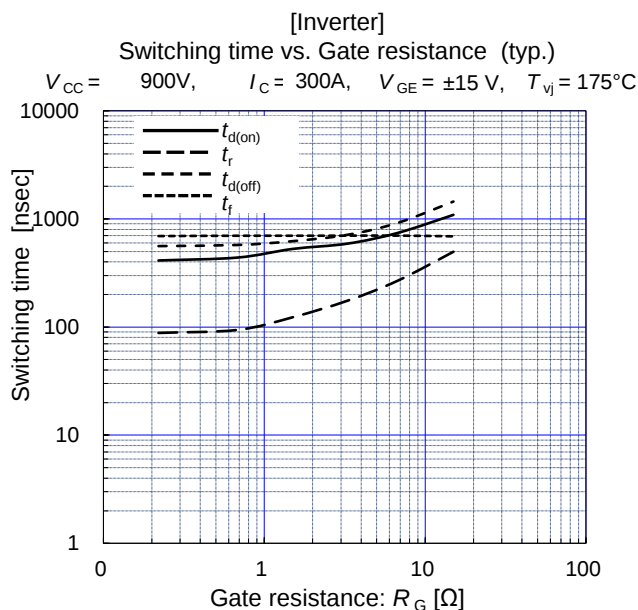
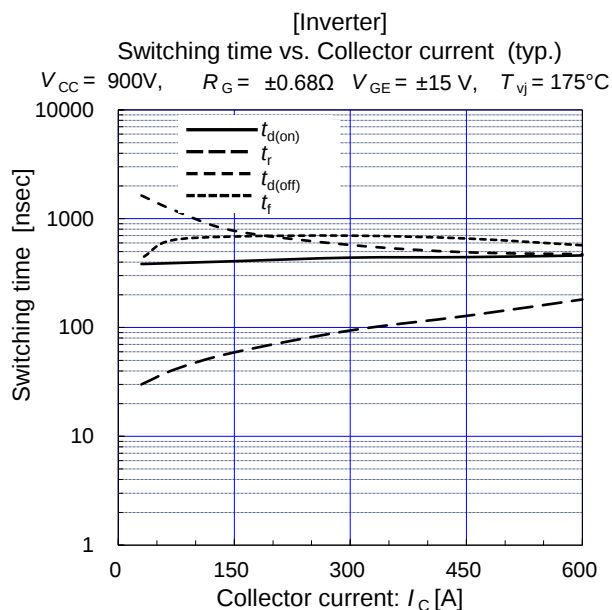
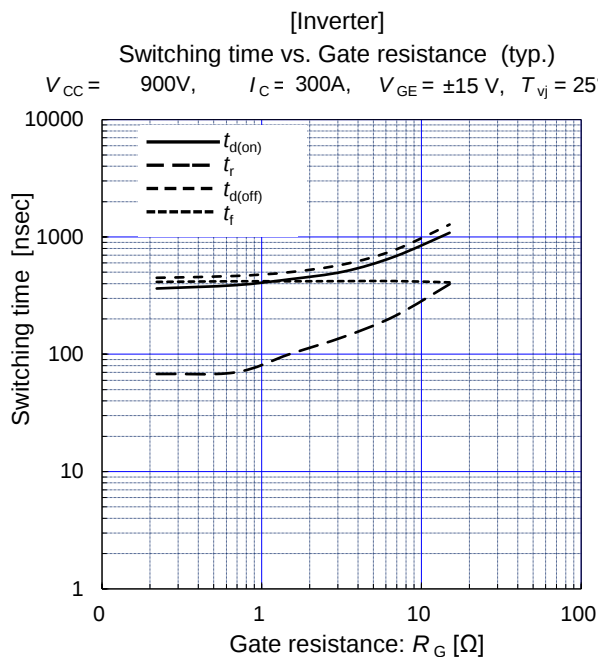
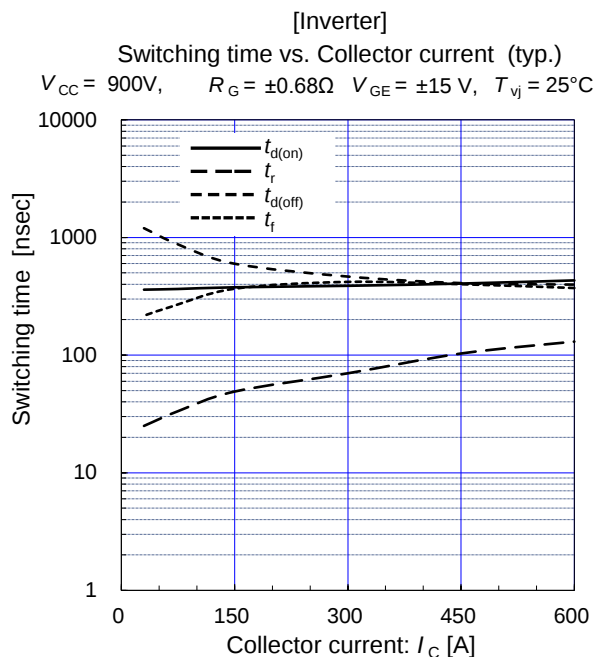
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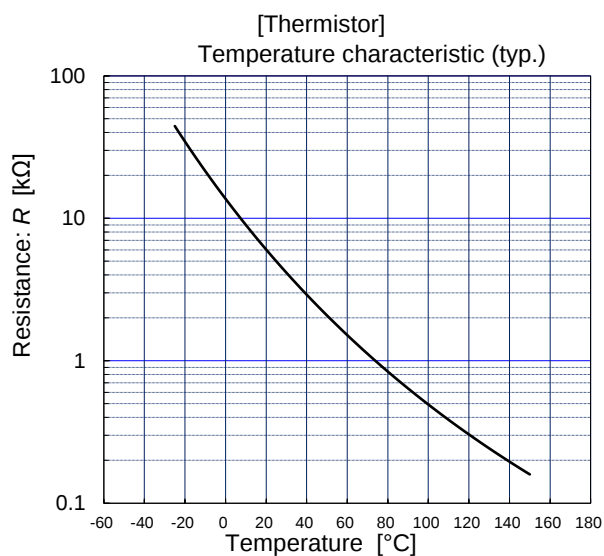
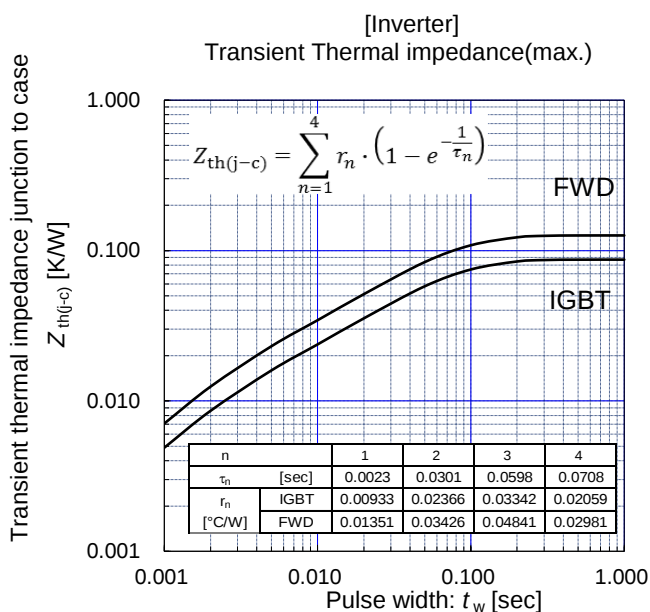
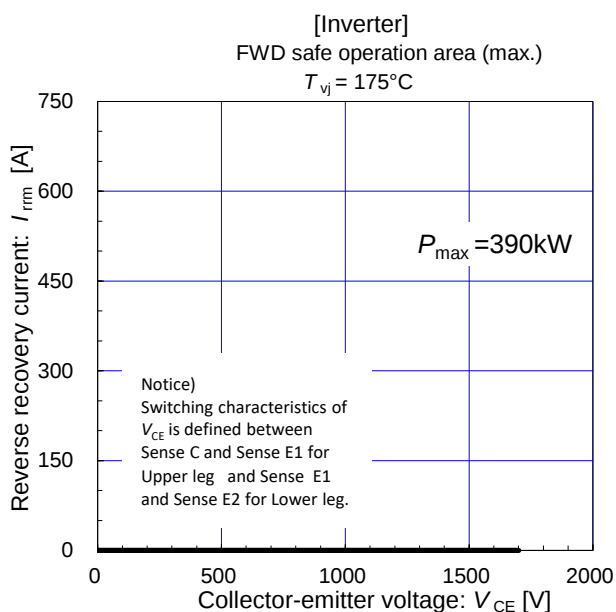
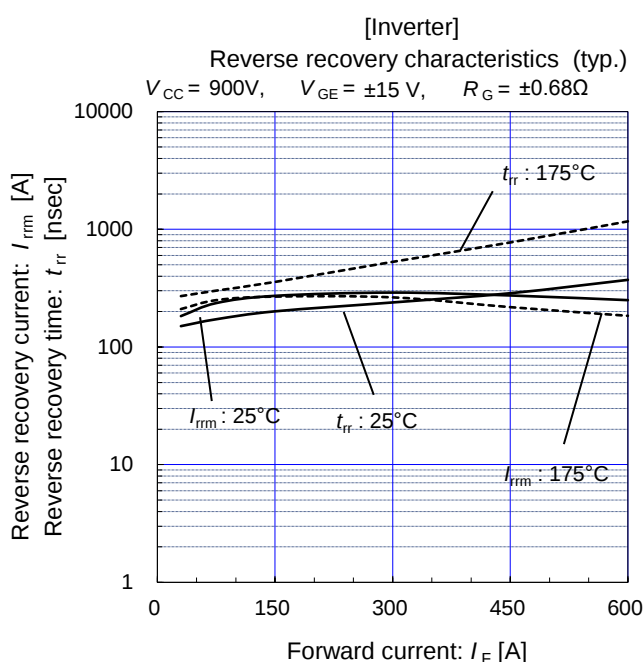
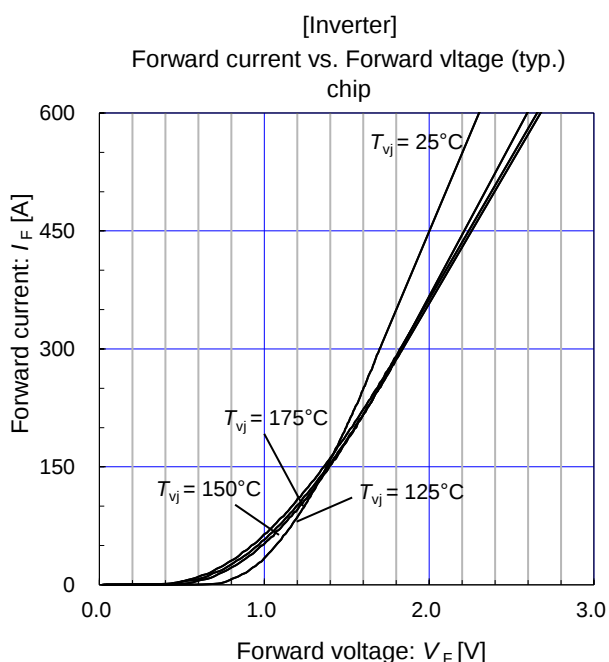
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